NSN 5961-01-331-1057

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-331-1057 **Inclosure Material:** Metal **Overall Length:** Between 0.085 inches and 0.097 inches **Terminal Length:** Between 0.060 inches and 0.064 inches **Overall Diameter:** Between 0.119 inches and 0.127 inches **Function For Which Designed:** Switching **End Application:** An/tyq-2 (v) 1 tactical air operations central **Mounting Method: Terminal Features Provided:** Hermetically sealed case and gold plated leads **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 reverse voltage, dc and 1.0 forward voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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